

INCHANGE SEMICONDUCTOR

Isc P-Channel MOSFET Transistor

BUZ172

FEATURES

- With TO-220 package
- · Low input capacitance and gate charges
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Switching applications
- · Load switch
- Power management

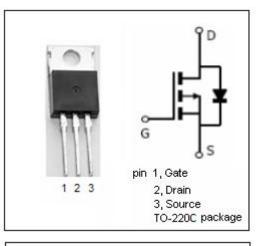
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

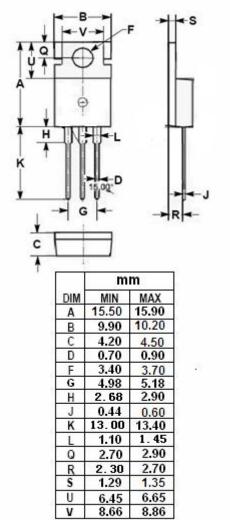
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	-100	V	
V _{GSS}	Gate-Source Voltage	±20	v	
ID	Drain Current-Continuous	-5.5	A	
I _{DM}	Drain Current-Single Pulsed	-22	A	
PD	Total Dissipation @T _C =25°C	40	W	
Tj	Max. Operating Junction Temperature	150	°C	
T _{stg}	Storage Temperature	-55~150	°C	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	3.1	°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance	75	°C /W	

1





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ELECTRICAL CHARACTERISTICS

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = -0.25mA	-100			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =-10V; I _D =-1mA	-2.1		-4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = -10V; I _D =-3.7A		400	600	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =-100V; V _{GS} = 0V			-1	μA
V _{SDF}	Diode forward voltage	I _{SD} =-11A, V _{GS} = 0 V		-1.0	-1.3	V

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2